## NSN 5961-01-179-4842

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View Online at https://aerobasegroup.com/nsn/5961-01-179-4842

Inclosure Material:
Metal
Overall Length:
0.190 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.220 inches
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-18
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
6.0 emitter to base voltage, static, collector open and 60.0 collector to base voltage/static/emitter open and 45.0 collector to emitter
voltage/static/base open
Current Rating Per Characteristic:
30.00 milliamperes source cutoff current
Power Rating Per Characteristic:
0.6 watts small-signal input power, common-collector preset
Transfer Ratio:
360.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Precious Material And Location:
Lead surfaces gold
Precious Material:
Gold
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:

N/a

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Demilitarization:

No

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